

SOLUTIONS: ECE 305 Homework 1: Week 1

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- 1) Ge has the same crystal structure (diamond) as Si, with a lattice constant of $a = 5.64$ Angstroms = 0.564 nm . Find the atomic density (atoms/cm³) and the spacing between nearest-neighbor atoms in Ge. Recall that $1 \text{ nm} = 1 \times 10^{-7} \text{ cm}$.

Solution:

Volume of the cubic unit cell: $V_u = a^3$ ($a = 0.564 \times 10^{-7} \text{ cm}$)

Number of atoms in the cubic unit cell: $N_u = 8 \times \frac{1}{8} + 6 \times \frac{1}{2} + 4 = 8$

(Eight on the corners, shared with 8 neighbors + 6 on the faces, each one shared with a nearest neighbor + 4 in the interior.) See Fig. 1.4 Pierret.

$$\text{Atomic density: } \frac{N_u}{V_u} = \frac{8}{a^3} = \frac{8}{(0.564 \times 10^{-7})^3} = 4.46 \times 10^{22} \text{ atoms/cm}^3$$

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Note: Proper MKS units would be atoms/m³, but for semiconductor work, it is common to use cm. **Be careful about units!**

The nearest neighbor to an atom is $\frac{1}{4}$ of the body diagonal away. The body diagonal of a cube of side, a , is $\sqrt{3}a$, so the NN spacing is

$$d_{NN} = \frac{\sqrt{3}a}{4} = \frac{\sqrt{3}(0.564 \text{ nm})}{4} = 0.244 \text{ nm}$$

$d_{NN} = 0.244 \text{ nm}$

- 2) Gallium arsenide (GaAs) has a zinc-blende crystal structure. Answer the following questions about GaAs. (Assume a lattice spacing of $a = 5.65$ Angstroms = 0.565 nm .)
- What is the density of GaAs in gm/cm³?
 - How many atoms/cm³ are there in GaAs?
 - How many valence electrons per cm³ are there in GaAs?
 - What is the closest spacing between adjacent arsenic atoms in GaAs?

ECE 305 Homework 1 Solutions: Week 1 (continued)**Solution:****2a)**

8 atoms per unit cell: 4 Ga and 4 As

atomic weights:

$$\text{Ga} = 69.72 \text{ Da or u}$$

$$\text{As} = 74.92$$

$$1 \text{ u} = 1.660 \times 10^{-27} \text{ kg}$$

$$\text{Total mass in unit cell: } M = 4 \times (69.72 + 74.92) \times 1.660 \times 10^{-27} \text{ kg}$$

Density = mass/volume:

$$\rho = \frac{9.60 \times 10^{-25} \text{ kg}}{(5.65 \times 10^{-10})^3} = 5.32 \times 10^3 \text{ kg/m}^3$$

(These are proper MKS units. Also called International System of Units.)

$$\rho = 5.32 \times 10^3 \frac{\text{kg}}{\text{m}^3} \times \frac{10^3 \text{ gm}}{\text{kg}} \times \frac{1}{(10^2 \text{ cm/m})^3} = 5.32 \frac{\text{gm}}{\text{cm}^3}$$

$$\boxed{\rho = 5.32 \frac{\text{gm}}{\text{cm}^3}}$$

2b)

$$\text{Atomic density: } \frac{N_u}{V_u} = \frac{8}{a^3} = \frac{8}{(0.565 \times 10^{-7})^3} = 4.44 \times 10^{22} \text{ atom/cm}^3$$

$$\boxed{\frac{N_u}{V_u} = 4.44 \times 10^{22} \text{ atom/cm}^3}$$

Note that GaAs and Ge have almost exactly the same lattice constant and the same crystal structure, so they have almost exactly the same atomic density.

2c)

Ga has 3 valence electrons (column III of periodic table)

As has 5 valence electrons (column IV of periodic table)

The unit cell has 4 Ga atoms and 4 As atoms

$$\frac{N_{ve}}{V_u} = \frac{4(3+5)}{a^3} = \frac{32}{(0.565 \times 10^{-7})^3} = 1.77 \times 10^{23} \text{ valence electrons/cm}^3$$

$$\boxed{\frac{N_{ve}}{V_u} = 1.77 \times 10^{23} \text{ valence electrons/cm}^3}$$

ECE 305 Homework 1 **Solutions:** Week 1 (continued) 2d)

The nearest neighbor of an As atom is a Ga atom and vice versa. Consider Fig. 1.4(c) in SDF. If the atom in the **upper left** is As, then the nearest neighbor is the Ga atom in the middle. The nearest **As atom** is the one on the top face at the **back right** of the cube. The distance is

$$d_{As-As} = \frac{a}{\sqrt{2}} = \frac{0.565 \text{ nm}}{\sqrt{2}} = 0.400 \text{ nm} \quad \boxed{d_{As-As} = 0.400 \text{ nm}}$$

3) Silicon (Si) has a diamond crystal structure. Answer the following questions about Si. (Assume a lattice spacing of $a = 5.42$ Angstroms.)

- Compute the density of Si atoms per cm^2 on $\{100\}$ planes.
- Treat atoms as rigid spheres with radii equal to one-half of the distance between nearest neighbors. Compute the percentage of volume occupied by the Si atoms.

Solution:

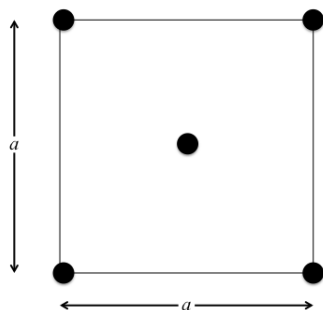
3a)

Consider the top face of the unit cell in Fig. 1.4 (a). As shown below, there are 5 atoms on the face, but the 4 on the corners are shared between 4 adjacent unit cells, so the total

number is $N = 4 \times \frac{1}{4} + 1 = 2$ per face of a cell. The density per unit area is

$$N_s = \frac{2}{a^2} = \frac{2}{(5.42 \times 10^{-8} \text{ cm})^2} = 6.81 \times 10^{14} \text{ cm}^{-2} \quad \boxed{N_s = 6.81 \times 10^{14} \text{ cm}^{-2}}$$

Note that the corresponding answer for a $\{111\}$ plane is $N_s = 7.86 \times 10^{14} \text{ cm}^{-2}$, but the geometry is a bit harder to visualize.



ECE 305 Homework 1 Solutions: Week 1 (continued)**3b)**

The volume of each sphere is $V_{\text{sphere}} = \frac{4}{3}\pi R^3$

The radius is one-half the nearest neighbor distance, so

$$R = \frac{1}{2} \left(\frac{\sqrt{3}a}{4} \right) = \frac{\sqrt{3}a}{8}$$

$$V_{\text{sphere}} = \frac{4}{3}\pi R^3 = \frac{4}{3}\pi \left(\frac{\sqrt{3}a}{8} \right)^3 = \frac{4}{3}\pi \frac{3\sqrt{3}a^3}{64} = \frac{\pi\sqrt{3}a^3}{16}$$

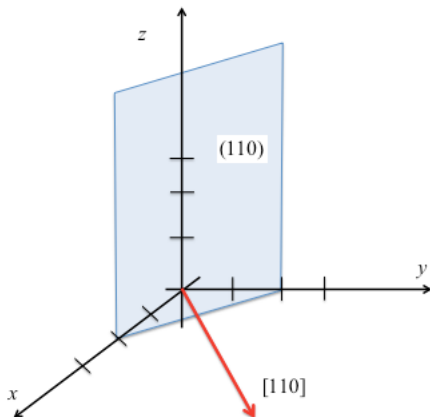
There are eight of these spheres in a unit cell, so the fraction of the unit cell volume filled (the packing fraction, PF ,) is

$$PF = \frac{8V_{\text{sphere}}}{a^3} = \frac{\sqrt{3}\pi}{16} = 0.34 \quad \boxed{PF = 0.34}$$

4) What is the angle between a $[110]$ direction and a (110) plane?

Solution:

The plane and direction are shown below.

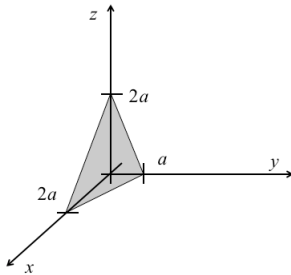


Note that the $[110]$ direction is normal to the (110) plane. **The angle is 90 degrees.** In general, one can prove that a $[hkl]$ direction is normal to an (hkl) plane.

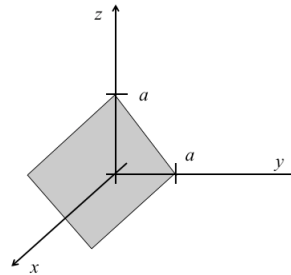
ECE 305 Homework 1 Solutions: Week 1 (continued)

5) Determine the Miller indices for the following planes along with the directions normal to each plane. (Use the general result from problem 4.)

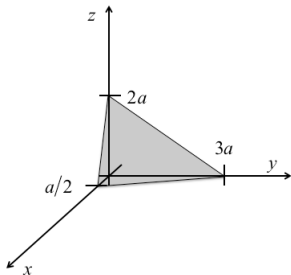
a)



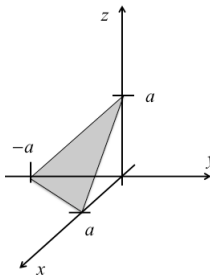
b)



c)



d)

**Solution:**

- 5a) Find the intercepts with the x, y, z, axes: 2, 1, 2 (in units of a)
 invert the intercepts: $1/2, 1, 1/2$
 multiply by 2 to produce integers: 1, 2, 1
 put in parentheses to denote a plane (1, 2, 1)
 direction normal to this plane is [1, 2, 1]

(1 2 1) plane [1 2 1] normal to the plane

- 5b) Find the intercepts with the x, y, z, axes: infinity, 1, 1 (in units of a)
 invert the intercepts: 0, 1, 1
 multiply by 1 to produce integers: 0, 1, 1
 put in parentheses to denote a plane (0, 1, 1)
 direction normal to this plane is [0, 1, 1]

(001) plane [001] normal to the plane

ECE 305 Homework 1 Solutions: Week 1 (continued)

- 5c) Find the intercepts with the x, y, z, axes: $1/2, 3, 2$ (in units of a)
 invert the intercepts: $2, 1/3, 1/2$
 multiply by 6 to produce integers: $12, 2, 3$
 put in parentheses to denote a plane $(12, 2, 3)$
 direction normal to this plane is $[12, 2, 3]$

$(12\ 2\ 3)$ plane

$[12\ 2\ 3]$ normal to the plane

- 5d) Find the intercepts with the x, y, z, axes: $1, -1, 1$ (in units of a)
 invert the intercepts: $1, -1, 1$
 multiply by 1 to produce integers: $1, -1, 1$
 put in parentheses to denote a plane $(1, -1, 1)$
 direction normal to this plane is $[1, -1, 1]$

$(1\ \bar{1}\ 1)$ plane

$[1\ \bar{1}\ 1]$ normal to the plane

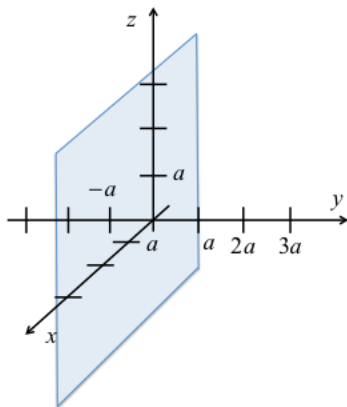
*** Note: when writing Miller indices, a bar over a number denotes a negative sign.

- 6) Sketch the following

- a) (010)
- b) $[010]$
- c) (203)
- d) $(\bar{1}1\bar{1})$

Solution:

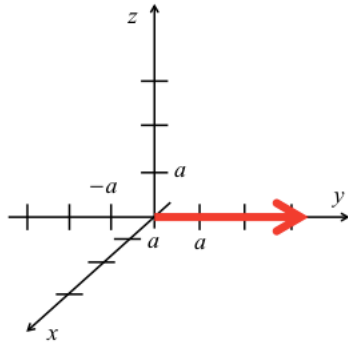
- 6a) (010) is a plane



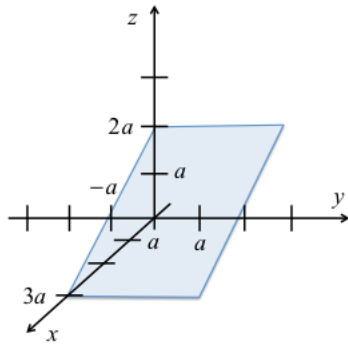
Note that a similar plane with a y-intercept at $2a$, or $3a$ would also be an (010) plane.

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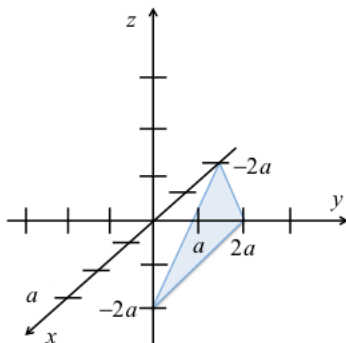
6b) $[010]$ is a direction normal to the plane in 6a)



6c) (203) is a plane



6d) $(\bar{1}1\bar{1})$ is a plane



Note that a similar plane with intercepts at $x = -a, y = a, z = -a$ would also be a $(\bar{1}1\bar{1})$ plane. In general, $\{h, k, l\}$ denotes a family of planes.

ECE 305 Homework 1 Solutions: Week 1 (continued)

- 7) Consider a hydrogen atom (1 electron orbiting one proton). Suppose that we excite the electron from the ground state to the first excited state (see Fig. 2.1).
- The electron relaxes to the ground state and emits a photon. What is the energy of this photon (in eV)?
 - What is the wavelength, λ , of the photon in vacuum? It may be helpful to recall that $E = h\nu$, where h is Planck's constant and ν is the frequency, and $c = \lambda\nu$, where c is the speed of light. **Pay attention to units.**

Solution:

7a) From Fig. 2.1:

$$E_0 = -13.6 \text{ eV (ground state)}$$

$$E_1 = -3.4 \text{ eV (first excited state)}$$

(Note that $E = 0$ is the energy of the electron infinitely far away from the proton.)

$$E_{ph} = -3.4 - (-13.6) = 10.2 \text{ eV (photon energy)} \quad \boxed{E_{ph} = 10.2 \text{ eV}}$$

$$\text{b) } \lambda = \frac{c}{\nu} = \frac{c}{E_{ph}/h} = \frac{hc}{E_{ph}}$$

$$\lambda = \frac{hc}{E_{ph}} = \frac{(6.626 \times 10^{-34} \text{ J-s})(3 \times 10^8 \text{ m/s})}{9.8 \times (1.6 \times 10^{-19}) \text{ J}} = 1.27 \times 10^{-7} \text{ m}$$

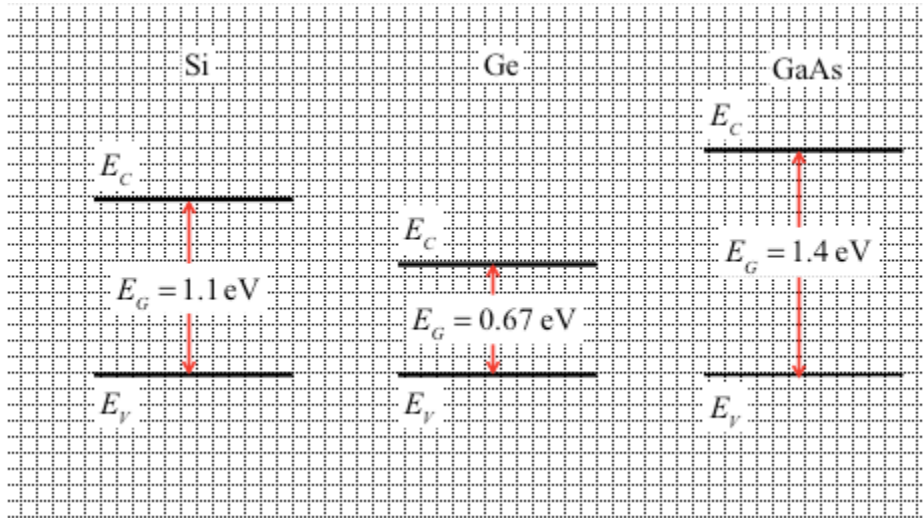
Careful: Be sure to use MKS units – meters for distance, meters/second for velocity, and Joules for energy.

$$\boxed{\lambda_{ph} = 127 \text{ nm}}$$

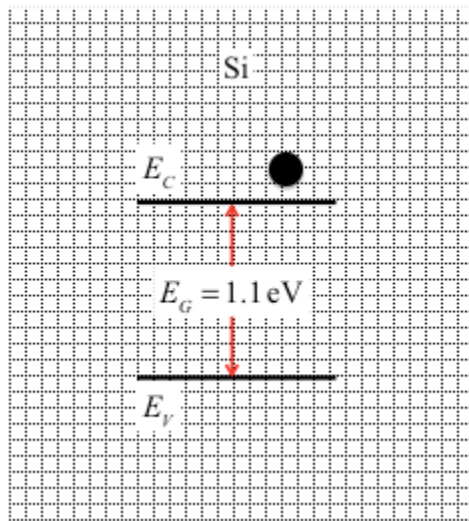
- 8) Consider Si ($E_G = 1.1 \text{ eV}$), Ge ($E_G = 0.67 \text{ eV}$) and GaAs ($E_G = 1.4 \text{ eV}$).
- Using the same vertical scale, draw a simple energy band diagram (showing E_C and E_V) for each of the three materials.
 - On the energy band diagram for Si, illustrate an electron in the conduction band.
 - On the energy band diagram for Ge, illustrate a hole in the valence band.

ECE 305 Homework 1 Solutions: Week 1 (continued)**Solution:**

a)



b) An electron in the conduction band is a filled state in the conduction band. It is a carrier of negative charge.



ECE 305 Homework 1 Solutions: Week 1 (continued)

- c) A hole in the valence band is an empty state in the valence band. It is a carrier of positive charge.

